Colossal Magnetoresistance by Avoiding a Ferromagnetic State in the Mott System Ca₃Ru₂O₇

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Transport and magnetic studies of $Ca_3Ru_2O_7$ for temperatures ranging from 0.4 to 56 K and magnetic fields B up to 45 T lead to strikingly different behavior when the field is applied along the different crystal axes. A ferromagnetic (FM) state with full spin polarization is achieved for the $B \parallel a$ axis, but colossal magnetoresistance is realized *only* for the $B \parallel b$ axis. For the $B \parallel c$ axis, Shubnikov–de Haas oscillations are observed and followed by a less resistive state than that for $B \parallel a$. Hence, in contrast with standard colossal magnetoresistive materials, the FM phase is the *least favorable* for electron hopping. These properties together with highly unusual spin-charge-lattice coupling near the Mott transition (48 K) are driven by the orbital degrees of freedom.

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In ruthenates, in particular, the bilayered $Ca_3Ru_2O_7$, the orbital degrees of freedom play an important role prompting novel phenomena through the coupling of the orbits to the spin (spin-orbit interaction) and to the lattice (Jahn-Teller effect). The extension of the 4d orbitals leads to comparable and thus competing energies for the crystalline fields, Hund's rule interactions, spin-orbit coupling, p-d hybridization, and electron-lattice coupling. Physical properties are then particularly susceptible to small perturbations by external magnetic fields and slight structural changes. Colossal magnetoresistance (CMR) normally occurs for the field applied along the easy axis of magnetization. In this Letter, we present evidence for an unusual CMR in $Ca_3Ru_2O_7$ realized only when B is perpendicular to the easy axis of magnetization (a axis) or when the spinpolarized state is avoided. This CMR phenomenon is fundamentally different from those of all other magnetoresistive systems, which are primarily driven by spin polarization. In addition, for the $B \parallel c$ axis, Shubnikov– de Haas oscillations are observed and followed by a much more conducting state than that for $B \parallel a$. The results in this Letter include the resistivity for the current along the c axis, ρ_c , and along the a axis, ρ_a , taken in B up to 45 T at $0.4~\mathrm{K}$ and the field dependence of the magnetization M and ρ_c in the vicinity of $T_{\rm MI}$ (40 \leq T < 56 K) for B applied along the a, b, and c axes. All results provide a coherent picture illustrating that the spin-polarized state is energetically the *least favorable* for electron hopping, and that orbital order and its coupling to lattice and spin degrees of freedom drive the exotic electronic and magnetic properties of Ca₃Ru₂O₇.

In the ruthenates with Ru^{4+} ($4d^4$) ions, the Hund's rule energy maximizing the total spin at each Ru site is not large enough to overcome the e_g - t_{2g} crystalline field splitting, so that the e_g levels are not populated. Hence, one t_{2g} orbital is doubly occupied, while the other two host a single electron each. The three t_{2g} levels (d_{xy} , d_{zx} , and d_{yz}) are expected to have different energies because the RuO₆

octahedra are deformed (all lattice parameters are different). These splittings are larger than the thermal energy k_BT and the Zeeman effect. The octahedra are corner shared and often tilted. The tilting plays an important role in the overlap between orbitals of neighboring octahedra. Small changes in the tilting can result in qualitative changes in the properties. Local density approximation calculations for Sr₃Ru₂O₇, which shares common aspects with Ca₃Ru₂O₇, find the Fermi surface very sensitive to small structural changes which readily shift the Fermi energy [1]. In view of the strong sensitivity to crystalline field and tilting angle asymmetries, the coupling of the magnetic field to the system depends on the orientation of the field. Consequently, different properties can be expected if the magnetic field is applied along the different crystallographic axes.

The Mott transition in the single-layered $Ca_{2-x}Sr_xRuO_4$ has been attributed theoretically [2-5] and experimentally [6,7] to Coulomb interactions and orbital ordering (OO). The wealth of experimental results for the bilayered Ca₃Ru₂O₇ still needs interpretation, but its origin is likely to be OO [8–19]. The crystal structure of Ca₃Ru₂O₇ is severely distorted by a tilt of the RuO₆ octahedra [9], which projects primarily onto the ac plane (153.22°), while it only slightly affects the bc plane (172.0°) [9]. These crucial bond angles directly impact the band structure and are the origin of the anisotropic properties of the compound. In zero field, Ca₃Ru₂O₇ undergoes an antiferromagnetic (AFM) transition at $T_N = 56$ K while remaining metallic, and then a Mott-like transition at $T_{\rm MI}=48~{\rm K}$ [8-19] with a dramatic reduction (up to a factor of 20) in the conductivity for $T < T_{\rm MI}$ [8–12]. This transition is accompanied by an abrupt shortening of the c-axis lattice parameter below $T_{\rm MI}$ [10]. Such magnetoelastic coupling results in Jahn-Teller distortions of the RuO₆ octahedra [9,10], thus lowering d_{xy} orbitals relative to d_{zx} and d_{yx} orbitals with a possible orbital distribution of $(n_{xy}, n_{zx}/n_{yz}) = (2, 2)$ [18]. Consequently, an AFM and

OO phase can occur, explaining the poor metallic behavior for $T < T_{\rm MI}$ and $B < B_c$ (critical field for the metamagnetic transition). This is consistent with Raman-scattering studies of Ca₃Ru₂O₇ revealing that the transition at $T_{\rm MI}$ is associated with the opening of a charge gap, $\Delta_c \sim 0.1$ eV, and the concomitant softening and broadening of an out-of-phase O phonon mode [13,14,18].

Single crystals were grown using both flux and floating zone techniques [20] and characterized by single crystal x-ray diffraction, Laue x-ray diffraction, scanning electron microscopy, and TEM. All results indicate that the single crystals are of high quality. The highly anisotropic magnetic properties of Ca₃Ru₂O₇ are used to determine the magnetic easy *a* axis and to identify twinned crystals that often show a small kink at 48 K in the *b*-axis susceptibility.

Shown in Fig. 1 is the field dependence of the resistivity for the c axis (interplane) ρ_c (right scale) for T = 0.4 K and $0 \le B \le 45$ T with $B \parallel a, b$, and c axes. ρ_c is extraordinarily sensitive to the orientation of B. For the $B \parallel a$ axis (magnetic easy axis), ρ_c shows an abrupt drop by an order of magnitude at 6 T, corresponding to the first-order metamagnetic transition leading to the spin-polarized or ferromagnetic (FM) state with a saturated moment M_s of $1.8\mu_B/\text{Ru}$ or more than 85% polarized spins (see left scale in Fig. 1) [8,9]. The reduction of ρ_c is attributed to the coherent motion of electrons between Ru-O planes separated by insulating Ca-O planes, a situation similar to spinfilters where the probability of tunneling depends on the angle between the spin magnetization of adjacent ferromagnets. The fully spin-polarized state can lower the resistivity by at most a factor of 10. As B is increased further from 6 to 45 T, ρ_c increases linearly with B by more than 30%, which is interesting in its own right since a quadratic

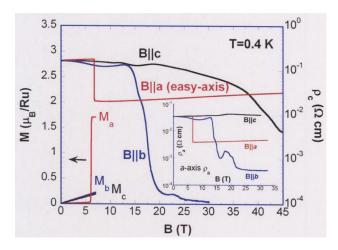


FIG. 1 (color online). Isothermal magnetization M for the $B \parallel a, b$, and c axes at T=2 K (left scale). Magnetic field dependence of the c-axis resistivity ρ_c for the $B \parallel a, b,$ and c axes at T=0.4 K (right scale). Note that the magnetic easy axis is along the a axis with spin polarization of more than 85%. Inset: B dependence of the a-axis resistivity ρ_a for the $B \parallel a, b$, and c axes at T=0.4 K.

dependence is expected for regular metals [21]. Because spin scattering is already reduced to its minimum at B = 6 T, the linear increase can arise only from orbital degrees of freedom that via spin-orbit coupling hinder the electrons from hopping.

For the $B \parallel b$ axis (magnetic hard axis), there is no spin-flop transition and the system remains AFM. In sharp contrast with ρ_c for the $B \parallel a$ axis, ρ_c for the $B \parallel b$ axis rapidly decreases by as much as 3 orders of magnitude at $B_c=15$ T, 2 orders of magnitude more than that for $B \parallel a$, where spins are fully polarized. For the $B \parallel c$ axis, on the other hand, ρ_c displays Shubnikov-de Haas (SdH) oscillations with low frequencies of 28 and 10 T [22]. (The SdH effect reappears with vastly different behavior when B rotates within the B plane [23].) Remarkably, B for $B \parallel c$ and $B \parallel c$, respectively.

Since the fully polarized state for $B_{\parallel a} > 6$ T can reduce ρ by only 1 order of magnitude, so even the b-axis M were fully polarized at high fields, it still cannot account for the 3 orders of magnitude decrease in ρ_c when $B_{\parallel b} > 15$ T, indicating that the spin degree of freedom alone is not at all enough to explain the behavior observed in Fig. 1. It is striking that a fully spin-polarized state, which is essential for magnetoresistance in all other magnetoresistive materials [24,25], is the least favorable for conduction in Ca₃Ru₂O₇. It deserves mentioning that the resistivities ρ_a and ρ_c behave very similarly, as shown in the inset. For $B \parallel a$, the decrease in ρ_a is also 1 order of magnitude, the same as that of ρ_c , suggesting that the reduction in both ρ_a and ρ_c is driven by the same in-plane spin polarization. For $B \parallel b$, ρ_a decreases by 2 orders of magnitude when

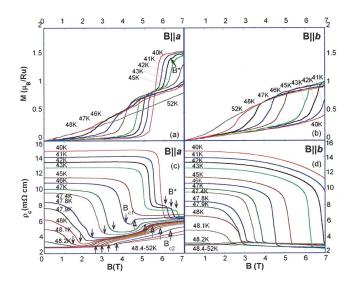


FIG. 2 (color). M and ρ_c as a function of B for the $B \parallel a$ axis [panels (a) and (c)] and the b axis [panels (b) and (d)] for $40 \le T < 56$ K. The solid arrows (open arrows) indicate B^* or B_{c1} (B_{c2}).

 $B>B_c$, confirming that the spin-polarized state is indeed not favorable for electron hopping. The striking behavior is that $\rho_a(\sim 10^{-3}~\Omega~{\rm cm})$ is larger than $\rho_c(\sim 10^{-4}~\Omega~{\rm cm})$ when $B>B_c$, although the opposite is true when $B<B_c$. There may be a change in effective dimensionality driven by B that results in incoherent-coherent and dimensional crossover and thus smaller interplane ρ_c when $B>B_c$. The crossover, if any, has a lesser impact on the intraplane ρ_a . This behavior driven by B could be analogous to that driven by temperature discussed in Ref. [26].

Shown in Fig. 2 are M and ρ_c as a function of B for the $B \parallel a$ and b axes for $40 \le T < 56$ K. The advantage of this temperature range is that B_c , along both the a and the b axis, falls within the range of 7 T, so that M can be fully characterized using a SQUID magnetometer. A direct comparison of ρ and M allows to further probe correlations and the role of OO. Figure 2(a) displays M as a function of B for the B \parallel a axis. At 40 K, M(B) is still very similar to M(B) at low temperatures (see Fig. 1) but with slightly lower M_s (= 1.6 μ_B/Ru) and B_c (= 5.8 T). For 41 \leq $T \le 45$ K, a second transition develops at $B^* > B_c$, suggesting an intermediate FM state for $B_c < B < B^*$, which is not fully polarized along the a axis. A possible interpretation is that the spins are rotating away from the a axis due to a shortening of the c axis near $T_{\rm MI}$, and hence a stronger field (B^*) is required to realign these spins along the a axis. Since the spin rotation tends to become stronger as T approaches T_{MI} , B^* increases with T. M is about $1\mu_B/\text{Ru}$ at B_c and increases by $0.6\mu_B/\text{Ru}$ at B^* . Only half of the ordered spins are thus aligned with the a axis in the spin reorientation (SR) region for $B_c < B < B^*$. B_c decreases with T and vanishes near T_N (= 56 K). Unlike M for the B \parallel a axis, M for the B \parallel b axis is unsaturated at $B > B_c$ and rounded at B_c without hysteresis, suggesting a second-order transition [see Fig. 2(b)]. Noticeably, the b-axis M at 7 T always converges to $\sim 1 \mu_B/\text{Ru}$, which is corresponding to 50% spin polarization and is independent of T. Clearly, M_s for the $B \parallel b$ axis is always smaller than that for the $B \parallel a$ axis in spite of the spin reorientation that partially enhances M for the $B \parallel b$ axis.

The corresponding ρ_c as a function of B for the $B \parallel a$ and b axes is displayed in Figs. 2(c) and 2(d), respectively. For the $B \parallel a$ axis, ρ_c at 40 K shows an abrupt drop at B_c similar to that at low temperatures with a magnetoresistance ratio $\Delta \rho/\rho(0)=58\%$, where $\Delta \rho=\rho(7~\mathrm{T})-\rho(0)$. In the range $41 \leq T \leq 45~\mathrm{K}$, ρ_c for $B \parallel a$ decreases initially at B_c , and then further at B^* with a total $\Delta \rho/\rho(0)$ similar to that at 40 K. Clearly, for $T \leq 45~\mathrm{K}$, ρ_c perfectly mirrors the behavior of M for the $B \parallel a$ axis, suggesting a strong spin-charge coupling in this region. However, for $T \geq 46~\mathrm{K}$, a valley develops in ρ_c ; the beginning and the end of this valley define two fields, B_{c1} ($B_{c1} = B_c$ for $T < 46~\mathrm{K}$) and B_{c2} . The valley broadens with increasing T (B_{c1} decreases with T, while B_{c2} increases) and changes its shape for $T \geq 48.2~\mathrm{K}$, where the slope at B_{c1} is now

positive and B_{c1} increases with T. An important point is that the field dependence of ρ_c for $46 \le T \le 52$ K does not track the field dependence of M [compare Figs. 2(a) and 2(c)]. This lack of parallel behavior of M and ρ_c is precisely a manifestation of the crucial role of the orbital degrees of freedom that dictate electron hopping for $B \parallel a$.

Furthermore, the reduction in ρ_c for the $B \parallel b$ axis [Fig. 2(d)] is always much larger than that for the $B \parallel a$ axis [Fig. 2(c)], and yet M_s for the $B \parallel b$ axis is always smaller than M_s for the $B \parallel a$ axis. For example, at 42 K and 7 T, $\Delta \rho / \rho(0) = 50\%$ with $M_s = 1.52 \mu_B / \text{Ru}$ for $B \parallel a$, and $\Delta \rho / \rho(0) = 80\%$ with $M_s = 1.03 \mu_B / \text{Ru}$ for $B \parallel b$. Note that the difference in both M_s and $\Delta \rho / \rho(0)$ between the $B \parallel a$ and b axes is ~35%. The temperature dependence of M(7 T) (left scale) and $\Delta \rho / \rho(0)$ at 7 T (right scale) for the $B \parallel a$ and b axes is summarized in Fig. 3(a). Such an inverse correlation between M and $\Delta \rho / \rho(0)$ suggests that the spin-polarized state is indeed detrimental to

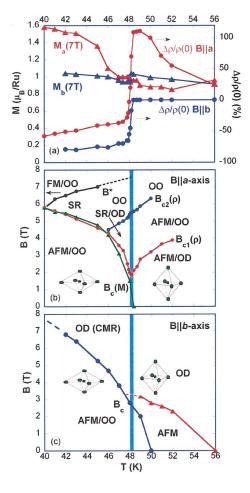


FIG. 3 (color). (a) Temperature dependence of M (triangles) and $\Delta \rho/\rho(0)$ (solid circles, right scale) at 7 T for the $B \parallel a$ and b axes. (b),(c) Phase diagrams plotted as B vs T summarizing various phases for the $B \parallel a$ and b axes, respectively. Note that in (b) $B_{c1}(\rho)$ and $B_{c2}(\rho)$ indicate the curves generated based on ρ , and $B_c(M)$ on M.

the CMR. For $T > T_{\rm MI}$, the metallic state is recovered for $B < B_{c1}$. However, applying B along the a axis leads to a rapid increase in ρ_c with positive $\Delta \rho / \rho(0)$ reaching as high as 112% for $B > B_{c2}$, whereas applying B along the b axis results in essentially no changes in ρ_c .

As is known, for B < 6 T, the Mott-like state is due to the OO facilitated by the c-axis shortening at $T_{\rm MI}$ [12,18]. When $B_{\parallel a} > 6$ T, the magnetic state becomes FM with the OO remained and stabilized by the FM state. The orbital order is either a ferro-orbital (FO) or an antiferro-orbital (AFO) configuration. Hence the system is in either a FM-FO or a FM-AFO state. The former inhibits the hopping of the 4d electrons because of the Pauli exclusion principle, while the latter permits intersite transitions but at the expense of the Coulomb energy. Therefore, despite an order of magnitude drop in ρ_c due to the spin polarization when B > 6 T, a fully metallic state can never be reached for the $B \parallel a$ axis. In fact, the linear increase in ρ_c with increasing B for $B_{\parallel a} > 6$ T, as shown in Fig. 1, may manifest a strengthened OO via the enhanced FM state. Conversely, applying B along the b axis steadily suppresses the AFM state [12], removing the orbital order through spin-orbit interaction when $B > B_c$. Such an orbitally disordered (OD) state drastically increases the electron mobility, therefore leading to CMR. On the other hand, applying B along the c axis has a noticeable impact on spin and orbital configurations when B > 35 T where ρ_c drops rapidly and becomes much smaller than ρ_c for the $B \parallel a$ axis. This suggests that the electronic state for the $B \parallel a$ axis is the most resistive one.

The magnetic and transport behavior shown in Fig. 2 is remarkably consistent with rapid changes of the Ru-O phonon frequency with B seen in Raman studies [Fig. 2(b) in Ref. [18]], providing complementary evidence for the evolution of the field-induced magnetic and orbital phases. While applying B along the b axis clearly favors CMR, applying the $B \parallel a$ axis generates a rich phase diagram [see Figs. 3(b) and 3(c)]. As shown in Fig. 3(b), below 40 K, B drives the system from an AFM-OO to a FM-OO state, and for 40 < T < 48 K the system enters a region of SR characterized by B_c and B^* . For $46 \le T <$ 48.2 K, the valley seen only in ρ_c signals an onset of an OD state at B_{c1} and then a reoccurring OO state at B_{c2} characterized by a sharp increase in ρ_c . For 48.2 < T <56 K, the system changes from an AFM-OD to an AFM-OO phase when $B > B_{c1}$. The evolution of the magneticorbital configuration is associated with the Jahn-Teller coupling, which appears in the vicinity of $T_{\rm MI}$.

We have presented evidence that the orbital degree of freedom and its coupling to spin and lattice play a critical role in $Ca_3Ru_2O_7$. As a consequence, applying B along the a, b, and c axes leads to novel and vastly different prop-

erties. Most notably, CMR achieved by avoiding the FM state is fundamentally different from that of all other magnetoresistive materials.

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